

November 1992 Revised February 2005

74VHC32 Quad 2-Input OR Gate

General Description

The VHC32 is an advanced high speed CMOS 2-Input OR Gate fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 4 stages including buffer output, which provide high noise immunity and stable output. An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High Speed:
 - t_{PD} = 3.8 ns (typ) at V_{CC} = 5V
- Low Power Dissipation: $I_{CC} = 2 \mu A \text{ (Max) at } T_A = 25^{\circ} C$
- High Noise Immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (Min)
- Power down protection is provided on all inputs
- Low Noise: $V_{OLP} = 0.8V$ (Max)
- Pin and Function Compatible with 74HC32

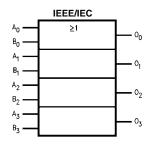
Ordering Code:

Order Number	Package Number	Package Description					
74VHC32M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow					
74VHC32MX_NL (Note 1)	M14A	Pb-Free 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow					
74VHC32SJ	M14D	Pb-Free 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide					
74VHC32MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide					
74VHC32MTCX_NL (Note 1)	MTC14	Pb-Free 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide					
74VHC32N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide					

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code. Pb-Free package per JEDEC J-STD-020B.

Note 1: "_NL" indicates Pb-Free package (per JEDEC J-STD-020B). Device available in Tape and Reel only.

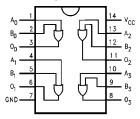
Logic Symbol



Pin Descriptions

Pin Names	Description				
A_n, B_n	Inputs				
O _n	Outputs				

Connection Diagram



Truth Table

В	0
Н	Н
Н	Н
L	Н
L	L
	Н

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Absolute Maximum Ratings(Note 2)

Recommended Operating Conditions (Note 3)

-0.5V to +7.0V Supply Voltage (V_{CC}) -0.5V to +7.0V DC Input Voltage (V_{IN}) DC Output Voltage (V_{OUT}) -0.5V to $V_{CC} + 0.5V$ Input Diode Current (I_{IK}) -20 mAOutput Diode Current (I_{OK}) ±20 mA

DC Output Current (I_{OUT}) ±25 mA DC V_{CC}/GND Current (I_{CC}) ±50 mA

 $-65^{\circ}C$ to $+150^{\circ}C$

260°C

Storage Temperature (T_{STG}) Lead Temperature (T_L)

(Soldering, 10 seconds)

Supply Voltage (V_{CC}) 2.0V to +5.5V Input Voltage (V_{IN}) 0V to +5.5V Output Voltage (V_{OUT}) 0V to V_{CC} Operating Temperature (T_{OPR}) -40°C to +85°C Input Rise and Fall Time (t_r, t_f)

 $V_{CC}=3.3V\pm0.3V$ 0 ~ 100 ns/V $V_{CC}=5.0V\pm0.5V$ 0 ~ 20 ns/V

Note 2: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifica-

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V _{cc}	T _A = 25°C			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Conditions	
Symbol	rarameter	(V)	Min Typ Max		Min	Max	Units	Conditions		
V _{IH}	HIGH Level	2.0	1.50			1.50		V		
	Input Voltage	3.0 – 5.5	0.7 V _{CC}			0.7 V _{CC}		V		
V _{IL}	LOW Level	2.0			0.50		0.50	V		<u> </u>
	Input Voltage	3.0 – 5.5			$0.3\mathrm{V}_{\mathrm{CC}}$		$0.3 V_{\rm CC}$	V		
V _{OH}	HIGH Level	2.0	1.9	2.0		1.9			$V_{IN}=V_{IH}$	$I_{OH} = -50 \mu A$
	Output Voltage	3.0	2.9	3.0		2.9		V	or V _{IL}	
		4.5	4.4	4.5		4.4				
		3.0	2.58			2.48		V		$I_{OH} = -4 \text{ mA}$
		4.5	3.94			3.80		V		$I_{OH} = -8 \text{ mA}$
V _{OL}	LOW Level	2.0		0.0	0.1		0.1		$V_{IN}=V_{IH} \\$	$I_{OL} = 50 \mu A$
	Output Voltage	3.0		0.0	0.1		0.1	V	or V _{IL}	
		4.5		0.0	0.1		0.1			
		3.0			0.36		0.44	V		I _{OL} = 4 mA
		4.5			0.36		0.44	V		$I_{OL} = 8 \text{ mA}$
I _{IN}	Input Leakage	0 – 5.5			±0.1		±1.0	μА	$V_{IN} = 5.5V$	or GND
	Current									
I _{CC}	Quiescent Supply Current	5.5			2.0		20.0	μΑ	$V_{IN} = V_{CC}$	or GND

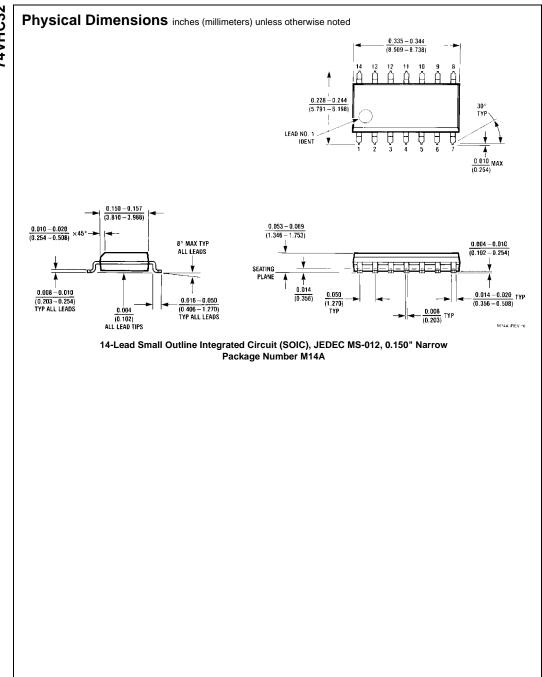
Noise Characteristics

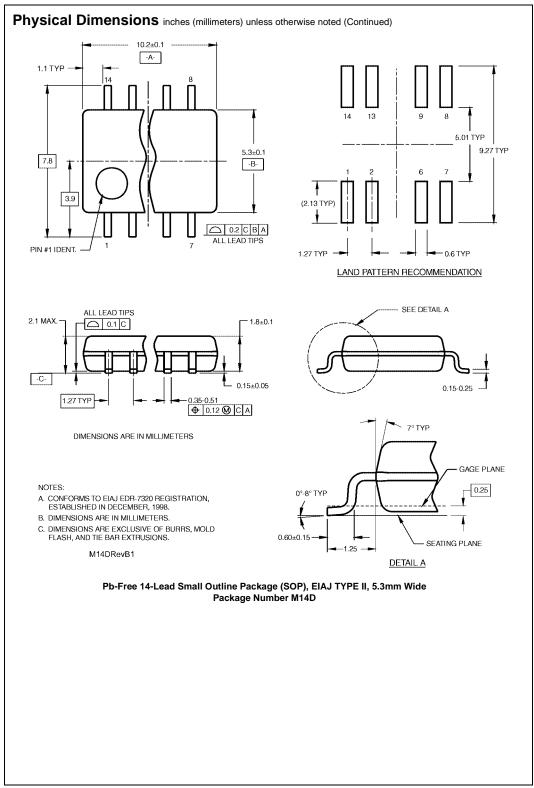
Symbol	Parameter	V _{CC} (V)	T _A =	25°C	Units	Conditions	
- Cy	, aramoto		Тур	Limit	00	1	
V _{OLP}	Quiet Output Maximum	5.0	0.3	8.0	V	C _L = 50 pF	
(Note 4)	Dynamic V _{OL}						
V _{OLV}	Quiet Output Minimum	5.0	-0.3	-0.8	V	C _L = 50 pF	
(Note 4)	Dynamic V _{OL}						
V _{IHD}	Minimum HIGH Level	5.0		3.5	V	C _L = 50 pF	
(Note 4)	Dynamic Input Voltage						
V _{ILD}	Maximum LOW Level	5.0		1.5	V	C _L = 50 pF	
(Note 4)	Dynamic Input Voltage						

Note 4: Parameter guaranteed by design.

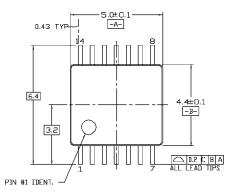
AC Electrical Characteristics									
Symbol	Parameter	V _{CC}	T _A = 25°C			T _A = -40°C to +85°C		Units	Conditions
		(V)	Min	Тур	Max	Min	Max	Ullits	Conditions
t _{PHL}	Propagation Delay	3.3		5.5	7.9	1.0	9.5	ns	C _L = 15 pF
t _{PLH}		±0.3		8.0	11.4	1.0	13.0	115	C _L = 50 pF
		5.0		3.8	5.5	1.0	6.5	ns	C _L = 15 pF
		±0.5		5.3	7.5	1.0	8.5	115	C _L = 50 pF
C _{IN}	Input Capacitance			4	10		10	pF	V _{CC} = Open
C _{PD}	Power Dissipation			14				pF	(Note 5)
	Capacitance								

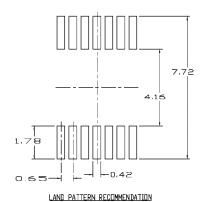
Note 5: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} * V_{CC} * f_{IN} + I_{CC} /4 (per gate).

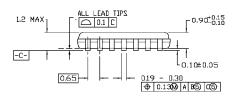


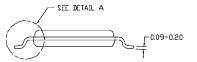


Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





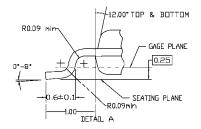




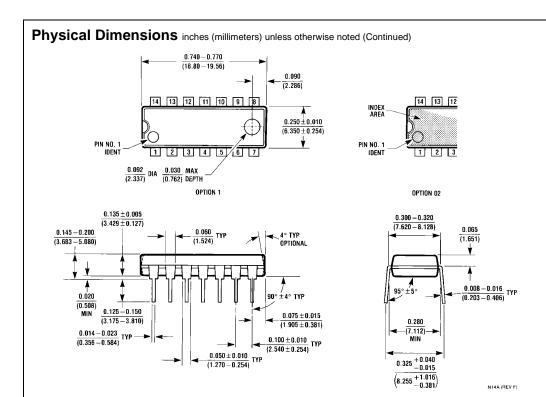
NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MO-153, VARIATION ABUREF NOTE 6, DATED 7/93
- B. DIMENSIONS ARE IN MILLIMETERS
- D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS D. DIMENSIONING AND TOLERANCES PER ANSI Y14.5M, 1982

MTC14revD



14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC14



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N14A

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